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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/943,667	08/31/2001	Shuichi Kikuchi	10417-094001	1120
26211 7	590 08/11/2004		EXAMINER	
	HARDSON P.C.		THOMAS, TONIAE M	
45 ROCKEFELLER PLAZA, SUITE 2800 NEW YORK, NY 10111		2800	ART UNIT	PAPER NUMBER
11211 101111,	,		2822	

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)	Applicant(s)		
Pagnanas ta Pula 242 Communication	09/943,667	KIKUCHI ET AL.			
Response to Rule 312 Communication	Examiner	Art Unit			
	Toniae M. Thomas	2822			
The MAILING DATE of this communication appears on the cover sheet with the correspondence address –					
·					
1. The amendment filed on 27 May 2004 under 37 CFR 1	1.312 has been considered, an	d has been:			
a) 🗌 entered.					
b) entered as directed to matters of form not affecting the scope of the invention.					
c) disapproved because the amendment was filed after the payment of the issue fee.					
Any amendment filed after the date the issue and the required fee to withdraw the application	·	ed by a petition under 37 CFR 1.3	13(c)(1)		
d) 🗵 disapproved. See explanation below.					
e) entered in part. See explanation below.					
See attachment.	C				
		Mary Wilczewski Primary Examper			

Application/Control Number: 09/943,667

Art Unit: 2822

Response to 312 Amendment

Claim 1 has been amended to recite the limitation "a first low concentration drain region of a second conductive type provided *adjacent to* one end of said gate electrode," and the limitation "a high concentration source region of the second conductive type provided *adjacent to* another end of said gate electrode." Similarly, claim 9 has been amended to recite the limitation "a first drain region provided *adjacent to* one end of said gate electrode," and the limitation "a source region provided *adjacent to* another end of said gate electrode."

The word adjacent means: close to, nearby, next to, adjoining. In figure 4 of the originally filed drawings, source region 10 is self-aligned with gate electrode 9. Figure 4 clearly shows the source region as being next to the gate electrode. Hence, the source region is *adjacent to* the gate electrode. This explicit definition of the term *adjacent to* is also found in the specification at page 12, lines 7-11.

While the source region 10 is adjacent to the gate electrode 9, the first drain region 5 is not. Figure 4 clearly shows the gate region overlapping the first drain region. In other words, the first drain region is not self-aligned with the gate electrode. Since the gate electrode overlaps the first drain region, the term adjacent to cannot be used to describe the structural relation of the first drain region to the gate electrode. Instead, the term subjacent to more accurately describes the structural relation of the first drain region to the gate

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electrode, since the first drain region is located beneath the gate electrode.

Hence, Applicant cannot claim "a first low concentration drain region of a second conductive type provided *adjacent to* one end of said gate electrode," as recited in claim 1, or "a first drain region provided *adjacent to* one end of said gate electrode," as recited in claim 9.

TMT

03 August 2004

Mary Wilczewski Primary Examiner